ORIGINAL PAPER

Magnetism and Conductivity Along Structural Domain Walls of \mbox{SrTiO}_3

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Abstract



The interface between the oxide insulators LaAlO₃ and SrTiO₃ (LAO/STO) hosts a two-dimensional electron gas. The combination of interfacial conductivity and superconductivity at ultra-low temperatures with the physical phenomena of the oxide parent materials has fueled extensive research in the field since its discovery in 2004. Scanning superconducting quantum interference device (SQUID) measurements have shown that structural domain walls, formed below 105 K, modulate the current flow at the interface and recently revealed weak magnetic signals along the same domain structure. Here we use scanning SQUID to investigate the temperature dependence of different electronic properties of the LAO/STO interface. We find correlation between magnetism and conductivity, which are both spatially modulated on the domain structure. This data suggests a possible relation between the populations of electrons participating in each order.

Keywords Oxide interfaces · Magnetism · Conductivity · Scanning SQUID microscopy · Polarity · Ferroelectricity

Strontium titanate (STO) is one of the most studied transition metal oxides in solid-state physics. It exhibits various unique properties such as very high dielectric constant at low temperatures [1], dilute superconductivity [2], and proximity to a quantum critical point [3] (between paraelectric and ferroelectric states). In addition, STO undergoes a structural phase transition at 105 K from cubic to tetragonal crystal structure [4]. In the tetragonal phase, the STO forms a dense network of structural domains separated by well-defined domain walls. Below ~ 37 K, the STO undergoes another transition where its dielectric constant rapidly increases, but a macroscopic ferroelectric state is not reached [5]. Salje et al. [6] used piezoelectric measurements

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to suggest that instead of a global ferroelectric state, the STO structural domain walls develop polarity below 40 K. Local measurements support this scenario [7]. Here we focus on properties that are modulated on the STO domain structure, and track their effects on the LAO/STO conductive interface [8–12]. Below ~ 37 K, the current flowing at the interface is modulated along the structural domain walls [13]. By combining transport with local imaging, it was shown that these modulations can induce significant anisotropy in the resistance of devices [14]. By using scanning stress measurements, where small changes in resistance are monitored as a function of local stress, indications of polarity at domain walls were found and were related to the spatial modulation in the current flow [7].

Here we use a scanning SQUID microscope to investigate the temperature dependence of different electronic properties of the LAO/STO interface [13] and in particular their modulations along the STO domain walls. The static magnetic landscape (Fig. 1 left column) corresponds to flux originating in local magnetic moments. This is a map of the magnetic field that threads the SQUID's pick-up loop (see illustrations in Fig. 1). The spatial distribution of the current flow (middle column) is obtained by mapping the Oersted magnetic fields that are generated by AC current flowing in the sample. The right column shows scanning stress measurements, which are maps of small changes in the four-

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Fig. 1 The temperature dependence of modulated magnetic and electronic properties along STO domain walls. Static magnetic signal (left), spatial distribution of current (middle), and electrical response to stress (right) simultaneously imaged by scanning SQUID. Both the response to stress and the current modulations increase as the temperature is lowered. The modulations of the magnetic signal show the opposite behavior, a reduced modulation at lower temperatures



probe resistance as a response to locally applied stress [7]. These small changes may indicate changes in polarity that are induced by local stress [7]. All images show the same area imaged at different temperatures. The main observable features in all three types of measurements are two stripes oriented in the [100] STO crystallographic direction. These stripes correspond to modulations of properties along the STO domain walls.

Our data shows that the temperature evolution of the response to stress [7] and the current modulations [13] are similar, decreasing in amplitude as the temperature is raised. Surprisingly, we found that as we increase the temperature, we observe stronger modulations in the D.C. magnetic signal (left column of Fig. 1), which are stress dependent [15].

These findings suggest that the magnetic signal is correlated to the conductivity at the interface. The fact that these properties, which are spatially modulated at the exact same locations, are anti-correlated as a function of temperature could fit a scenario where the populations of electrons involved in both behaviors (magnetism and conductivity) are related. Although the mechanisms governing the magnetism found at the LAO/STO interface are far from being clear, our results hint at a new direction where conduction electrons and magnetism may be linked [16].

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